DESIGNS AND ANALYSES OF SOME RF/MICROWAVE PASSIVE ELEMENTS ON CYLINDRICAL CPWS

V. Akan

Communication System Group TUBITAK Space Technologies Research Institute ODTU Kampusu Inonu Bulvari, TR-06531, Ankara, Turkiye

M. Duyar

Republic of Turkiye Ministry of Industry and Trade Ankara, Turkiye

E. Yazgan

Department of Electrical and Electronics Engineering Hacettepe University TR-06800, Ankara Turkiye

M. Bayrak

Faculty of Engineering Department of Electrical and Electronics Engineering Selcuk University Konya, Turkiye

Abstract—In this article, designs and analyses of several CCPW (Cylindrical CPW) discontinuities have been realized as microwave reactive elements. The quasi-TEM characteristic parameters of CCPWs have been obtained by CMT (Conformal Mapping Techniques) which provide satisfactory accuracy at microwave frequencies and lead to closed-form analytical solutions suitable for CAD software packages. Then these discontinuities have been simulated in CST Microwave Studio 2006 in order to obtain inductance, capacitance and also input impedance versus frequency and physical dimensions of the elements. The results show that CCPW

Corresponding author: E. Yazgan (yazgan@hacettepe.edu.tr).

discontinuities can be used successfully as reactive elements for related applications.

1. INTRODUCTION

There is a growing interest in non-planar transmission lines recently. Since these type transmission lines are quite flexible they can be especially applied in aircraft, missiles, and mobile communication applications in order to feed printed antennas around a non-planar surface like an elliptical or a cylindrical surface where the planar realization is not feasible as mentioned in [1, 2]. It is possible to construct cylindrical and/or elliptical transmission lines using appropriate dielectric materials easily. Up to date there are some studies about non-planar transmission lines to evaluate characteristic parameters of them analytically and accurately [1-5]. In addition, various planar and cylindrical CPW discontinuities have been analyzed in [6-8]. In these papers, mostly, similar capacitive elements have been taken into consideration for cylindrical applications. However, in this study it is aimed to analyze and design of CCPW short circuit inductive, CCPW open ended-capacitive and CCPW open circuit with gap-capacitive elements. In order to calculate the characteristic parameters of CCPWs CMT has been employed. These parameters are also verified by simulations in CST Microwave Studio 2006. Moreover, input impedance and inductance or capacitance values have been obtained according to defined line parameters. The realized calculations and simulations indicate that studied elements can be used easily in the related applications.

2. CALCULATION OF CHARACTERISTIC LINE PARAMETERS FOR CCPW

In Fig. 1, cross sectional view of the transmission line used to form CCPW discontinuities is seen with defined physical parameters. The characteristic impedance and effective dielectric constant of CCPW can be calculated as follows [3, 4, 9]

$$C_T = C_{01} + C_{03} + C_d \tag{1}$$

where C_0 and C_d capacitances stand for the free-space capacitance per unit length and the dielectric layer respectively. C_T also refers to total capacitance per unit length. Air capacitance can be expressed as:

$$C_{01} = C_{03} = 2\varepsilon_0 \frac{K(k_0)}{K(k'_0)} \tag{2}$$

where K(k) is the complete elliptic integral of the first kind. Similarly, the capacitance of the dielectric layer is,



Figure 1. The cross-sectional view of CCPW for the construction of the related discontinuities.

$$C_d = 2\varepsilon_0(\varepsilon_r - 1)\frac{K(k_d)}{K(k'_d)} \tag{3}$$

Then effective dielectric constant and characteristic impedance of CCPW can be written as

$$\varepsilon_{eff} = \frac{C_T}{C_0} = 1 + q(\varepsilon_r - 1) \tag{4}$$

where q is the filling factor that can be expressed as

$$q = \frac{1}{2} \frac{K(k_d) K(k'_0)}{K(k'_d) K(k_0)}$$
(5)

and finally the characteristic impedance relation can be obtained as

$$Z_0 = \frac{30\pi}{\sqrt{\varepsilon_{eff}}} \frac{K(k_0')}{K(k_0)} \tag{6}$$

The related modulus k_0 and k_d can be evaluated as in [9].



Figure 2. Planar visualization of CCPW short circuit inductive element where l = 1.65 mm.



Figure 3. (a) Inductance, (b) imaginary, and (c) real part of input impedance values of the CCPW short circuit inductive element.

3. CCPW DISCONTINUITIES

According to Fig. 1, 2Ψ and 2θ refer to central conductor width and total width of central conductor and gaps, respectively. r_1 , r_2 are inner and outer radius of dielectric material, respectively as well. All conductors are assumed as PEC and having zero thickness. Dielectric materials are also supposed as simple mediums. Through the analyses and designs all of the studied elements have been realized on 50 ohm CCPW, in this paper i.e., $2\Psi = 60^{\circ}$, $2\theta = 115.94^{\circ}$, $r_1 = 2.4$ mm, $r_2 = 6.2$ mm and $\varepsilon_r = 2.1$.

3.1. CCPW Short Circuit Element

In Fig. 2, the planar visualization of CCPW short circuit inductive element is shown with defined dimensions. In this case, when the element is excited current flows around joint of ground and signal conductors, then magnetic energy is stored behind this joint and this response increases the reactance inductively. In Fig. 3, real and imaginary parts of input impedance and inductance values are seen in 0.5–10 GHz frequency range for the given parameters.

3.2. CCPW Open Ended Element

This element again has the same cross sectional dimensions as seen in Fig. 1. Its planar illustration is also seen in Fig. 4. Similar to the short circuit element, because of abrupt change at the end, fringing fields arise and they give rise to stored electric energy. This case leads to increase in capacitive reactance. The obtained results for real and



Figure 4. Planar visualization of CCPW open ended capacitive element where l = 1.65 mm.



Figure 5. (a) Capacitance, (b) imaginary, and (c) real part of input impedance values of the CCPW open ended capacitive element.



Figure 6. The planar visualization of CCPW open circuit wit a gap capacitive element where l = 2 mm.

imaginary parts of input impedance and total capacitance value of this element are shown in Fig. 5 according to the defined parameters.

3.3. CCPW Open Circuit with a Gap

The last element is again a capacitive one. For cross sectional view Fig. 1 can be referenced and in Fig. 6 planar visualization of CCPW open circuit with a gap is seen with the related dimensions. For this element, because of the gap placed in the center conductor, there exists electric field that increases capacitive reactance. Simulation results for input impedance and total capacitance are shown in Fig. 7 for the related dimensions, and effect of gap length is clearly seen on capacitive reactance value.



Figure 7. (a) Capacitance, (b) imaginary, and (c) real part of input impedance values of the CCPW open circuit with a gap.

4. CONCLUSION

In this paper, CCPW short circuit element, CCPW open ended element and CCPW open circuit with a gap have been designed and simulated. First of all, the characteristic impedance and effective dielectric constant have been evaluated via CMT. Then using appropriate dimensions, the mentioned elements have been designed and simulated in CST Microwave Studio 2006. In addition, input impedance as real and imaginary parts, inductance and total capacitance have been presented for the simulated elements. The change of these obtained values versus freauency is similar to the results of planar cases. Briefly, in this article it is shown that RF/microwave reactive elements can be realized on CCPW type transmission lines. For the time being the experimental studies on these elements are going on, and as a future work they can be used for matching and feeding cylindrical wrap around type antennas.

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